Contents

Preface ix

SECTION I. THERMODYNAMICS – BULK GROWTH

P–T–X phase equilibrium and vapor pressure scanning of non-stoichiometry in CdTe
J.H. Greenberg 1
Growth and homogeneity region of CdTe
Yu.M. Ivanov 12
Effect of CdTe "postmelting"
L. Shcherbak, P. Feichouk and O. Panchouk 16
Growth and characterization of 100 mm diameter CdZnTe single crystals by the vertical gradient freezing method
T. Asahi, O. Oda, Y. Taniguchi and A. Koyama 20
Attempts to growth of undoped CdTe single crystals with high electrical resistivity
P. Rudolph, S. Kawasaki, S. Yamashita, S. Yamamoto, Y. Usuki, Y. Konagaya, S. Matada and T. Fukuda 28
Stress birefringence in vapour-grown CdTe and its correlation to the growth techniques
M. Laasch, G. Kloess, Th. Kunz, R. Schwarz, K. Grasza, C. Eiche and K.W. Benz 34
Comparison of Bridgman and THM method regarding the effect of In doping and distribution of Zn in CdTe
E. Weigel and G. Müller-Vogt 40
Growth and characterization of twin-free ZnSe single crystals by the vertical Bridgman method
T. Fukuda, K. Umetsu, P. Rudolph, H.J. Koh, S. Iida, H. Uchiki and N. Tsuboi 45
Vapour growth and characterization of bulk ZnSe single crystals
Yu.V. Korostelin, V.I. Kozlovsky, A.S. Nasibov and P.V. Shapkin 51
Seeded melt growth of ZnSe crystals under Zn partial pressure
I. Kikuma and T. Shiohara 60

SECTION II. DOPING AND PURIFICATION

Incorporation of dopants and native defects in bulk $Hg_{1-x}Cd_xTe$ crystals and epitaxial layers
H.R. Vydyanath 64
Fundamental studies of p-type doping of CdTe
H.L. Hwang, K.Y.J. Hsu and H.Y. Ueng 73
Transmutation doping of wide-bandgap II–VI compounds
M. Wienecke, J. Bollmann, J. Röhrich, K. Maass, B. Reinhold, D. Forkel-Wirth and The ISOLDE Collaboration 82
Generation of atomic group V materials for the p-type doping of wide gap II–VI semiconductors using a novel plasma cracker
H.-J. Lugauer, A. Waag, L. Worschech, W. Ossau and G. Landwehr 86
Evidence for thermodynamically stable p/n junction, formed by Ag doping of (Hg,Cd)Te
I. Lyubomirsky, V. Lyakhovitskaya, J.F. Guillemoles, I. Riess, R. Triboulet and D. Cahen 90
Purification methods of Cd, Te and CdTe and periodicity of segregation coefficients of admixtures
L. Kuchař, J. Drápala and J. Luňáček 94
Matrix and impurity element distributions in CdHgTe (CMT) and (Cd,Zn)(Te,Se) compounds by chemical analysis
P. Capper, E.S. O'Keefe, C. Maxey, D. Dutton, P. Mackett, C. Butler and I. Gale 104

SECTION III. DEFECTS

Native defect identification in II–VI materials
B.K. Meyer and W. Stadler 119
Defect recovery of ion-implanted CdTe
A. Burchard, R. Magerle, J. Freidinger, S.G. Jahn and M. Deicher 128
Cadmium vacancy related defects in MBE grown CdTe
L. Worschech, W. Ossau, F. Fischer, A. Waag and G. Landwehr 134
Characterization by diffuse X-ray scattering of damage in ion-implanted HgCdTe
A. Declémy and P.O. Renault 139

Point defects in Te-rich CdTe
O. Panchouk, P. Fochouk and P. Feichouk 144
Formation of low resistance contacts to p-CdTe by annealing autocatalytically deposited Ni–P alloy coatings
R.W. Miles, B. Ghosh, S. Duke, J.R. Bates, M.J. Carter, P.K. Datta and R. Hill 148
Electrically active defects in detector-grade CdTe:Cl and CdZnTe materials grown by THM and HPBM
L. Chibani, M. Hage-Ali and P. Siffert 153
Transmission electron microscopy of CdTe/CdS based solar cells
Y.Y. Loginov, K. Durose, H.M. Al-Allak, S.A. Galloway, S. Oktik, A.W. Brinkman, H. Richter and D. Bonnet 159
Conductivity conversion in CdTe layers
V. Valdna, F. Buschmann and E. Mellikov 164
Lattice sites of Li in CdTe
M. Restle, K. Bharuth-Ram, H. Quintel, C. Ronning, H. Hofsäss, U. Wahl, S.G. Jahn and The ISOLDE Collaboration 168
Thermal stability of substitutional Ag in CdTe
S.G. Jahn, The ISOLDE Collaboration, H. Hofsäss, M. Restle, C. Ronning, H. Quintel, K. Bharuth-Ram and U. Wahl 172
$ZnSe_{1-x}Te_x$ solid solutions
V. Valdna, J. Hiie, U. Kallavus, . A. Mere and T. Piibe 177
Palladium as impurity in ZnTe
S. Hermann, H.-E. Mahnke, D. Schumann, B. Spellmeyer, G. Sulzer, J. Bollmann, B. Reinhold, J. Röhrich, M. Wienecke, R. Yankov and H.-E. Gumlich 181
A-centers modifying in CdTe–Yb crystals
E.S. Nikonyuk, V.Z. Shlyakhovuy, M.O. Kovalets, M.I. Kuchma, Z.I. Zakharuk and V.M. Frasuniak 186
Luminescence and nonradiative deactivation of excited states involving oxygen defect centers in polycrystalline ZnO
H.-J. Egelhaaf and D. Oelkrug 190
Structural properties of CdTe and $Hg_{1-x}Cd_xTe$ epitaxial layers grown on sapphire substrates
N.V. Sochinskii, J.C. Soares, E. Alves, M.F. da Silva, P. Franzosi, S. Bernardi and E. Diéguez 195
Ordered phase in HgCdTe thin films grown by reactive deposition in RF mercury glow discharge
L.G. Mansurov and V.G. Savitsky 201

SECTION IV. COMPENSATION

Fundamental studies on compensation mechanisms in II–VI compounds
Y. Marfaing 205
Self-compensation in halogen doped CdTe grown by molecular beam epitaxy
F. Fischer, A. Waag, L. Worschech, W. Ossau, S. Scholl, G. Landwehr, J. Mäkinen, P. Hautojärvi and C. Corbel 214
Self-compensation studies in Cd-saturated In-doped CdTe
L. Shcherbak, P. Feichouk, P. Fochouk and O. Panchouk 219

SECTION V. DIFFUSION

Two stream diffusion of Hg into CdTe
M.U. Ahmed, E.D. Jones, J.B. Mullin and N.M. Stewart 223
Diffusivity of mercury vacancies in $Hg_{0.8}Cd_{0.2}Te$
M. Neubert and K. Jacobs 229
Oscillations of the composition of HgCdTe solid solution after laser annealing
R. Ciach, M. Faryna, M. Kuźma, M. Pociask and E. Sheregii 234

SECTION VI. TRANSITION ELEMENTS AND PHOTOREFRACTIVITY

Transition-metal impurities in II–VI semiconductors: characterization and switching of charge states
J. Kreissl and H.-J. Schulz 239
Influence of zinc on the photorefractivity behaviour of $Cd_{1-x}Zn_xTe$:V
G. Martel, J.Y. Moisan, B. Lambert, M. Gauneau, S. Stephan, N. Wolffer, P. Gravey, A. Aoudia, E. Rzepka, Y. Marfaing, R. Triboulet, M.C. Busch, M. Hadj-Ali, J.M. Koebel, P. Siffert, G. Bremond, A. Zerrai and G. Marrakchi 250
Vanadium in CdTe
P. Christmann, J. Kreissl, D.M. Hofmann, B.K. Meyer, R. Schwarz and K.W. Benz 259
Relationship between deep levels in vanadium-doped CdTe and photorefractive effect
A. Zerrai, G. Marrakchi, G. Bremond, J.Y. Moisan, G. Martel, M. Gauneau, B. Lambert, P. Gravey, N. Wolffer, A. Aoudia, Y. Marfaing, R. Triboulet, J.M. Koebel, M. Hadj-Ali and P. Siffert 264

Noncontact characterization of CdTe doped with V or Ti
C. Eiche, W. Joerger, R. Schwarz and K.W. Benz 271
Identification of titanium dopants in CdS, CdSe and Cd(S,Se) crystals by luminescence and EPR methods
P. Peka, M.U. Lehr, H.-J. Schulz, J. Dziesiaty and S. Müller 277
Deep electron states in gallium-doped CdMnTe mixed crystals
J. Szatkowski, E. Płaczek-Popko, A. Hajdusianek and B. Bieg 282
Defects study by photoluminescence and cathodoluminescence in vanadium doped CdZnTe
E. Rzepka, A. Lusson, A. Riviere, A. Aoudia, Y. Marfaing and R. Triboulet 286

Author index 292
Subject index 296